**Datasheet** 

## **M.2 (S42) 3TG6-P** series

- SATA III soultion for industrial field
- Exclusive L<sup>3</sup> architecture
- AES-256bits encryption
- Excellent random performance
- Supports TRIM/NCQ/SMART
- Built in iData Guard
- Compatible with M.2 2242-D2-B-M standard
- Designed with hardware LDPC ECC engine



## Introduction

Innodisk M.2 (S42) 3TG6-P is SATA III 6.0 Gb/s flash based disk, which delivers excellent performance, especially in random data transfer rate, and which offers reliability making it the ideal solution for a variety of applications, including embedded system, industrial computing, and enterprise field. M.2 (S42) 3TG6-P not only performs unmatched performance, but also designed with Innodisk owned technical knowhow to ensure the data integrity and highest levels of reliability.

Innodisk M.2 (S42) 3TG6-P is designed for industrial field, and supports several standard features, including TRIM, NCQ, and S.M.A.R.T. In addition, Innodisk's exclusive industrial-oriented firmware provides a flexible customization service, making it perfect for a variety of industrial applications.



# **M.2 (S42)** 3TG6-P series

## Contact us for more information about the M.2 (S42) 3TG6-P

Innodisk is a service-driven provider of industrial embedded flash and DRAM storage products and technologies, with a focus on the cloud computing, industrial/embedded, and aerospace and defense industries.

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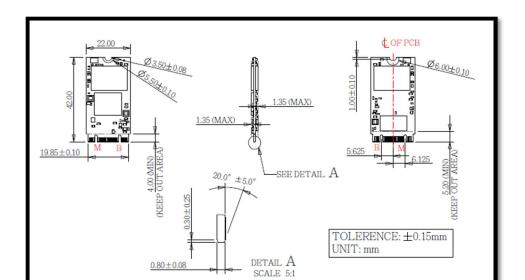
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**Specifications** 

**Diagram** 

Specifications			
Interface	SATA III		
Flash Type	3D TLC		
P/E cycle	3,000		
Capacity	128GB~512GB		
Max. Channels	4		
Sequential R/W (MB/sec, max.)	560/510		
Max. Power Consumption	2.44W (739mAx3.3V)		
Thermal Sensor	$\checkmark$		
External DRAM buffer	$\checkmark$		
H/W Write Protect	-		
ATA Security √			
S.M.A.R.T.	$\checkmark$		
Dimension (WxLxH)	22.0 X 42.0 X 3.5 mm		
Environment	Vibration: 20G @7~2000Hz Shock: 1500G @ 0.5ms Storage Temperature: -55°C ~ +95°C MTBF: 3 million hours		

**Ordering Information** 

Operation Temp.	128GB	256GB	512GB
Standard Grade	DGM24-	DGM24-	DGM24-
(0°C ~ +70°C)	A28M71ECAQF	B56M71ECAQF	C12M71ECAQF
Industrial Grade	DGM24-	DGM24-	DGM24-
(-40°C ~ +85°C)	A28M71EWAQF	B56M71EWAQF	C12M71EWAQF

